General Purpose Transistors

NPN Silicon

These transistors are designed for general purpose amplifier applications. They are housed in the SC-75/SOT-416 package which is designed for low power surface mount applications.

Features

- NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP Capable
- Pb–Free Packages are Available

MAXIMUM RATINGS ($T_A = 25^{\circ}C$)

| Rating | Symbol | Мах | Unit |
|--------------------------------|------------------|-----|------|
| Collector-Emitter Voltage | V _{CEO} | 45 | V |
| Collector-Base Voltage | V _{CBO} | 50 | V |
| Emitter-Base Voltage | V _{EBO} | 6.0 | V |
| Collector Current – Continuous | Ι _C | 100 | mAdc |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

THERMAL CHARACTERISTICS

| Characteristic | Symbol | Max | Unit |
|-----------------------------------------------------------------------------------------------|-----------------------------------|----------------|-------------|
| Total Device Dissipation, FR-4 Board (Note 1) $T_A = 25^{\circ}C$ | P _D | 200 | mW |
| Derated above 25°C | | 1.6 | mW/°C |
| Thermal Resistance, Junction-to-Ambient (Note 1) | R_{\thetaJA} | 600 | °C/W |
| Total Device Dissipation, FR-4 Board (Note 2) $T_A = 25^{\circ}C$ Derated above 25°C | P _D | 300 2.4 | mW mW/°C |
| | | | |
| Thermal Resistance, Junction-to-Ambient (Note 2) | $R_{	hetaJA}$ | 400 | °C/W |
| Junction and Storage Temperature Range | T _J , T _{stg} | –55 to +150 | °C |

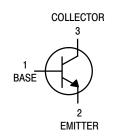
1. FR-4 @ min pad.

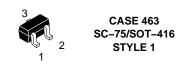
2. FR-4 @ 1.0 × 1.0 in pad.



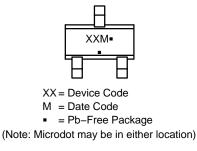
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MARKING DIAGRAM



ORDERING INFORMATION

See detailed ordering, marking and shipping information in the package dimensions section on page 5 of this data sheet.

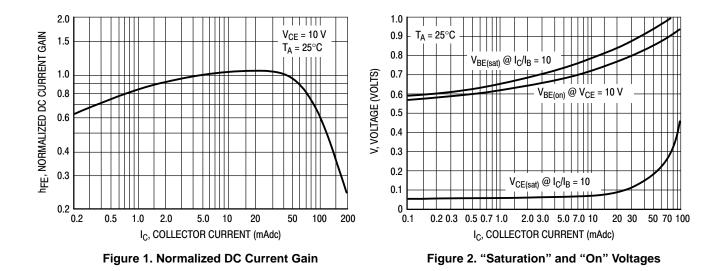
ELECTRICAL CHARACTERISTICS ($T_A = 25^{\circ}C$ unless otherwise noted)

(I_C = 0.2 mA, V_{CE} = 5.0 Vdc, R_S = 2.0 k\Omega, f = 1.0 kHz, BW = 200 Hz)

| Characteristic | Symbol | Min | Тур | Max | Unit | |
|----------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------------|-----------------------------------------------|----------------------|-------------------|-------------------|-------------------|----------|
| OFF CHARACTERISTICS | | | | | | • |
| Collector – Emitter Breakdown Voltage $(I_C = 10 \text{ mA})$ | BC847 Series | V _{(BR)CEO} | 45 | _ | _ | V |
| Collector – Emitter Breakdown Voltage $(I_C = 10 \ \mu A, \ V_{EB} = 0)$ | BC847 Series | V _{(BR)CES} | 50 | _ | _ | V |
| Collector – Base Breakdown Voltage $(I_C = 10 \ \mu A)$ | BC847 Series | V _{(BR)CBO} | 50 | _ | _ | V |
| Emitter-Base Breakdown Voltage $(I_E = 1.0 \ \mu A)$ | BC847 Series | V _{(BR)EBO} | 6.0 | _ | _ | V |
| Collector Cutoff Current (V _{CB} = 30 V) (V | _{CB} = 30 V, T _A = 150°C) | I _{CBO} | - | | 15 5.0 | nA μA |
| ON CHARACTERISTICS | | <u>.</u> | | | | |
| DC Current Gain (I _C = 10 μ A, V _{CE} = 5.0 V) | BC847A BC847B BC847C | h _{FE} | - - - | 90 150 270 | - - - | _ |
| $(I_{C} = 2.0 \text{ mA}, V_{CE} = 5.0 \text{ V})$ | BC847A BC847B BC847C | | 110 200 420 | 180 290 520 | 220 450 800 | |
| Collector – Emitter Saturation Voltage (I _C = 10 mA, I _B = 0.5 mA) (I _C = 100 mA, I _B = 5.0 mA) | | V _{CE(sat)} | - | | 0.25 0.6 | V |
| Base – Emitter Saturation Voltage ($I_C = 10 \text{ mA}, I_B = 0.5 \text{ mA}$) ($I_C = 100 \text{ mA}, I_B = 5.0 \text{ mA}$) | | V _{BE(sat)} | - | 0.7 0.9 | _ _ | V |
| Base – Emitter Voltage (I _C = 2.0 mA, V _{CE} = 5.0 V) (I _C = 10 mA, V _{CE} = 5.0 V) | | V _{BE(on)} | 580 - | 660 - | 700 770 | mV |
| SMALL-SIGNAL CHARACTERISTICS | | | | • | • | • |
| Current-Gain – Bandwidth Product ($I_C = 10 \text{ mA}, V_{CE} = 5.0 \text{ Vdc}, f = 100 \text{ MHz}$) | | f _T | 100 | - | _ | MHz |
| Output Capacitance (V _{CB} = 10 V, f = 1.0 MHz) | | C _{obo} | _ | - | 4.5 | pF |
| Noise Figure $(1 - 0.2 \text{ mA})/(1 - 0.5 \text{ mA})/(1 - 0.5$ | | NF | | | 10 | dB |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

10



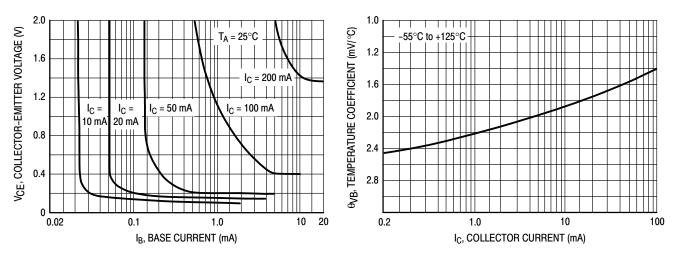


Figure 3. Collector Saturation Region



BC847

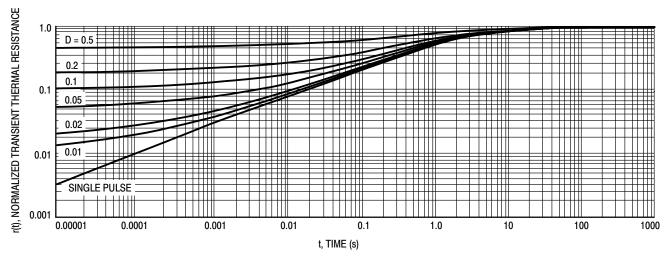
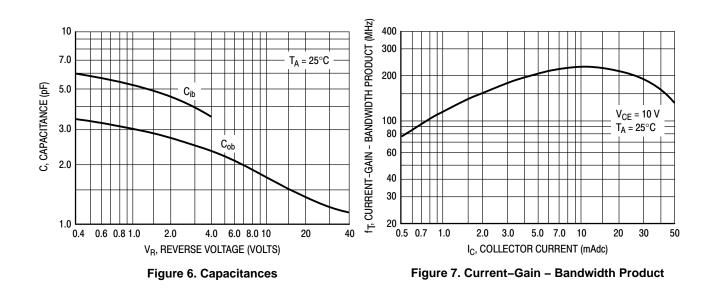


Figure 5. Normalized Thermal Response



ORDERING INFORMATION

| Device | Marking | Package | Shipping [†] |
|----------------|---------|----------------------------|-----------------------|
| BC847ATT1 | 1E | SC-75/SOT-416 | 3,000 / Tape & Reel |
| BC847BTT1 | 1F | SC-75/SOT-416 | |
| BC847BTT1G | 1F | SC-75/SOT-416 (Pb-Free) | 3,000 / Tape & Reel |
| NSVBC847BTT1G* | 1F | SC-75/SOT-416 (Pb-Free) | 3,000 / Tape & Reel |
| BC847CTT1G | 1G | SC-75/SOT-416 (Pb-Free) | 3,000 / Tape & Reel |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D. *NSV Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC–Q101 Qualified and PPAP

Capable.





*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

1.000

0.039

SCALE 10:1

mm

inches

0.508

0.020

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 DESCRIPTION:
 SC-75/SOT-416
 PAGE 1 OF 1

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